

## features

- Dual-Input, Single-Output MOSFET Switch With No Reverse Current Flow (No Parasitic Diodes)
- IN1 . . . 250-mΩ, 500-mA N-Channel; 18-µA Supply Current
- IN2 . . . 1.3-Ω, 100-mA P-Channel; 0.75-µA Supply Current (V<sub>AUX</sub> Mode)
- Advanced Switch Control Logic
- CMOS and TTL Compatible Enable Input
- Controlled Rise, Fall, and Transition Times
- 2.7 V to 5.5 V Operating Range
- SOT-23-5 and SOIC-8 Package
- –40°C to 85°C Ambient Temperature Range
- 2-kV Human Body Model, 750-V Charged Device Model, 200-V Machine-Model ESD Protection

## typical applications

- Notebook and Desktop PCs
- Cell phone, Palmtops, and PDAs
- Battery Management

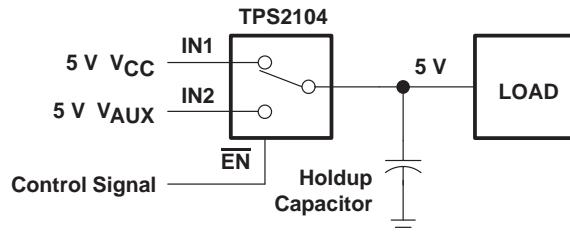
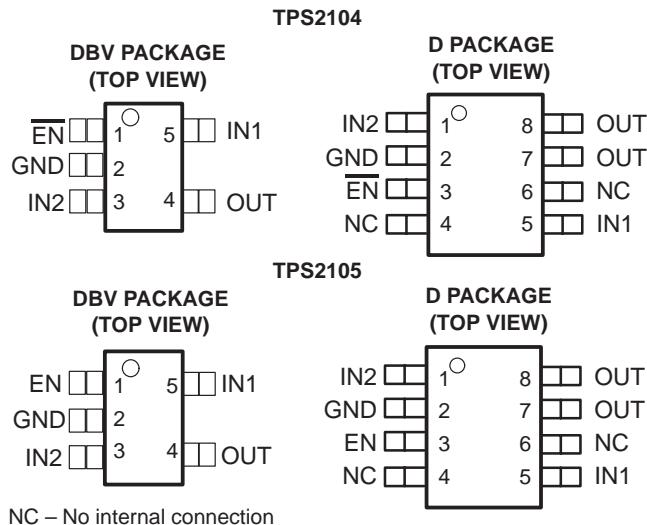


Figure 1. Typical Dual-Input Single-Output Application

## description

The TPS2104 and TPS2105 are dual-input, single-output power switches designed to provide uninterrupted output voltage when transitioning between two independent power supplies. Both devices combine one n-channel (250 mΩ) and one p-channel (1.3 Ω) MOSFET with a single output. The p-channel MOSFET (IN2) is used with auxiliary power supplies that deliver lower current for standby modes. The n-channel MOSFET (IN1) is used with a main power supply that delivers higher current required for normal operation. Low on-resistance makes the n-channel the ideal path for higher main supply current when power-supply regulation and system voltage drops are critical. When using the p-channel MOSFET, quiescent current is reduced to 0.75 µA to decrease the demand on the standby power supply. The MOSFETs in the TPS2104 and TPS2105 do not have the parasitic diodes, typically found in discrete MOSFETs, thereby preventing back-flow current when the switch is off.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

# TPS2104, TPS2105 V<sub>AUX</sub> POWER-DISTRIBUTION SWITCHES

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## Selection Guide, V<sub>AUX</sub> Power-Distribution Switches

| DEVICE  | ENABLE | OPERATING VOLTAGE RANGE (V) | MAXIMUM INPUT CURRENT, IN1 (mA) | MAXIMUM INPUT CURRENT, IN2 (mA) | AMBIENT TEMPERATURE RANGE (°C) |
|---------|--------|-----------------------------|---------------------------------|---------------------------------|--------------------------------|
| TPS2100 | EN     | 2.7 to 4                    | 500                             | 10                              | -40 to 70                      |
| TPS2101 | EN     | 2.7 to 4                    | 500                             | 10                              | -40 to 70                      |
| TPS2102 | EN     | 2.7 to 4                    | 500                             | 100                             | -40 to 70                      |
| TPS2103 | EN     | 2.7 to 4                    | 500                             | 100                             | -40 to 70                      |
| TPS2104 | EN     | 2.7 to 5.5                  | 500                             | 100                             | -40 to 85                      |
| TPS2105 | EN     | 2.7 to 5.5                  | 500                             | 100                             | -40 to 85                      |

### AVAILABLE OPTIONS FOR TPS2104, TPS2105

| TA            | DEVICE  | ENABLE | PACKAGED DEVICES            |            |
|---------------|---------|--------|-----------------------------|------------|
|               |         |        | SOT-23-5 (DBV) <sup>†</sup> | SOIC-8 (D) |
| -40°C to 85°C | TPS2104 | EN     | TSP2104DBV <sup>†</sup>     | TPS2104D   |
|               | TPS2105 | EN     | TSP2105DBV <sup>†</sup>     | TPS2105D   |

Both packages are available left-end taped and reeled. Add an R suffix to the D device type (e.g., TPS2105DR).

<sup>†</sup> Add T (e.g., TPS2104DBVT) to indicate tape and reel at order quantity of 250 parts.

Add R (e.g., TPS2104DBVR) to indicate tape and reel at order quantity of 3000 parts.

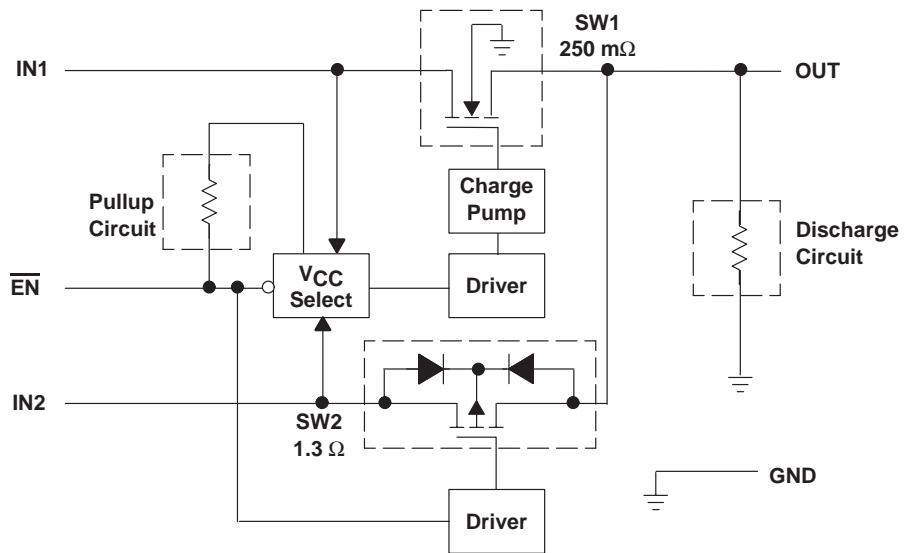
### Function Tables

| TPS2104 |      |    |      |
|---------|------|----|------|
| VIN1    | VIN2 | EN | OUT  |
| 0 V     | 0 V  | XX | GND  |
| 0 V     | 5 V  | L  | GND  |
| 5 V     | 0 V  | L  | VIN1 |
| 5 V     | 5 V  | L  | VIN1 |
| 0 V     | 5 V  | H  | VIN2 |
| 5 V     | 0 V  | H  | VIN2 |
| 5 V     | 5 V  | H  | VIN2 |

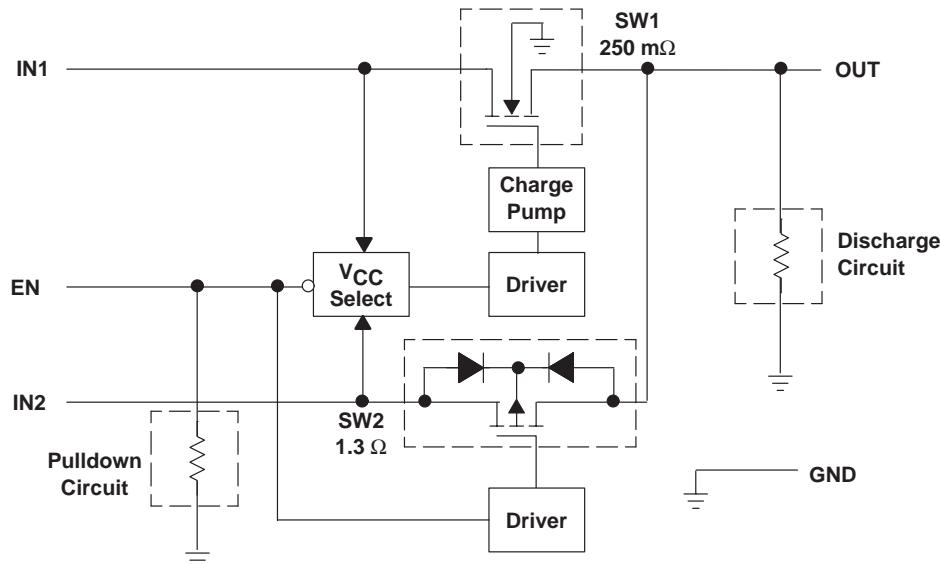
XX = don't care

| TPS2105 |      |    |      |
|---------|------|----|------|
| VIN1    | VIN2 | EN | OUT  |
| 0 V     | 0 V  | XX | GND  |
| 0 V     | 5 V  | H  | GND  |
| 5 V     | 0 V  | H  | VIN1 |
| 5 V     | 5 V  | H  | VIN1 |
| 0 V     | 5 V  | L  | VIN2 |
| 5 V     | 0 V  | L  | VIN2 |
| 5 V     | 5 V  | L  | VIN2 |

TPS2104 functional block diagram



TPS2105 functional block diagram



# TPS2104, TPS2105 V<sub>AUX</sub> POWER-DISTRIBUTION SWITCHES

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## Terminal Functions

| TERMINAL |         |      |         | I/O  | DESCRIPTION |  |  |
|----------|---------|------|---------|------|-------------|--|--|
| NAME     | NO.     |      |         |      |             |  |  |
|          | TPS2104 |      | TPS2105 |      |             |  |  |
|          | DBV     | D    | DBV     | D    |             |  |  |
| EN       |         |      | 1       | 3    | I           | Active-high enable for IN1-OUT switch                                |  |
| EN       | 1       | 3    |         |      | I           | Active-low enable for IN1-OUT switch                                 |  |
| GND      | 2       | 2    | 2       | 2    | I           | Ground   |  |
| IN1†     | 5       | 5    | 5       | 5    | I           | Main input voltage, NMOS drain (250 mΩ), require 0.22 µF bypass      |  |
| IN2†     | 3       | 1    | 3       | 1    | I           | Auxilliary input voltage, PMOS drain (1.3 Ω), require 0.22 µF bypass |  |
| OUT      | 4       | 7, 8 | 4       | 7, 8 | O           | Power switch output  |  |
| NC       |         | 4, 6 |         | 4, 6 |             | No connection  |  |

† Unused INx should not be grounded.

### detailed description

#### power switches

##### *n*-channel MOSFET

The IN1-OUT *n*-channel MOSFET power switch has a typical on-resistance of 250 mΩ at 5-V input voltage, and is configured as a high-side switch.

##### *p*-channel MOSFET

The IN2-OUT *p*-channel MOSFET power switch has a typical on-resistance of 1.3 Ω at 5-V input voltage and is configured as a high-side switch. When operating, the *p*-channel MOSFET quiescent current is reduced to typically 0.75 µA.

#### charge pump

An internal charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.7 V and requires very little supply current.

#### driver

The driver controls the gate voltage of the IN1-OUT and IN2-OUT power switches. To limit large current surges and reduce the associated electromagnetic interference (EMI) produced, the drivers incorporate circuitry that controls the rise times and fall times of the output voltage.

#### enable

The logic enable will turn on the IN2-OUT power switch when a logic high is present on  $\overline{\text{EN}}$  (TPS2104) or logic low is present on EN (TPS2105). A logic low input on  $\overline{\text{EN}}$  (TPS2104) or logic high on EN (TPS2105) restores bias to the drive and control circuits and turns on the IN1-OUT power switch. The enable input is compatible with both TTL and CMOS logic levels.



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**absolute maximum ratings over operating free-air temperature (unless otherwise noted)†**

|  |       |                              |
|--|-------|------------------------------|
| Input voltage range, V <sub>I</sub> (IN1) (see Note 1)                 | ..... | -0.3 V to 6 V                |
| Input voltage range, V <sub>I</sub> (IN2) (see Note 1)                 | ..... | -0.3 V to 6 V                |
| Input voltage range, V <sub>I</sub> at EN or EN (see Note 1)           | ..... | -0.3 V to 6 V                |
| Output voltage range, V <sub>O</sub> (see Note 1)                      | ..... | -0.3 V to 6 V                |
| Continuous output current, I <sub>O</sub> (IN1)                        | ..... | 700 mA                       |
| Continuous output current, I <sub>O</sub> (IN2)                        | ..... | 140 mA                       |
| Continuous total power dissipation                                     | ..... | See dissipation rating table |
| Operating virtual junction temperature range, T <sub>J</sub>           | ..... | -40°C to 125°C               |
| Storage temperature range, T <sub>STG</sub>                            | ..... | -65°C to 150°C               |
| Lead temperature soldering 1.6 mm (1/16 inch) from case for 10 seconds | ..... | 260°C                        |
| Electrostatic discharge (ESD) protection: Human body model             | ..... | 2 kV                         |
| Machine model  | ..... | 200 V                        |
| Charged device model   | ..... | 750 V                        |

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltages are with respect to GND.

DISSIPATION RATING TABLE

| PACKAGE | T <sub>A</sub> < 25°C<br>POWER RATING | DERATING FACTOR<br>ABOVE T <sub>A</sub> = 25°C | T <sub>A</sub> = 70°C<br>POWER RATING | T <sub>A</sub> = 85°C<br>POWER RATING |
|---------|---------------------------------------|--|---------------------------------------|---------------------------------------|
| DBV     | 309 mW                                | 3.1 mW/°C                                      | 170 mW                                | 123 mW                                |
| D       | 568 mW                                | 5.7 mW/°C                                      | 313 mW                                | 227 mW                                |

**recommended operating conditions**

|  | MIN   | MAX  | UNIT |
|--|-------|------|------|
| Input voltage, V <sub>I</sub> (INx)                    | 2.7   | 5.5  | V    |
| Input voltage, V <sub>I</sub> at EN and EN             | 0     | 5.5  | V    |
| Continuous output current, I <sub>O</sub> (IN1)        | ..... | 500  | mA   |
| Continuous output current, I <sub>O</sub> (IN2)        | ..... | 100† | mA   |
| Operating virtual junction temperature, T <sub>J</sub> | -40   | 125  | °C   |

† The device can deliver up to 220 mA at I<sub>O</sub>(IN2). However, operation at the higher current levels will result in greater voltage drop across the device, and greater voltage droop when switching between IN1 and IN2.

**electrical characteristics over recommended operating junction temperature range,  
V<sub>I</sub>(IN1) = V<sub>I</sub>(IN2) = 5 V, I<sub>O</sub> = rated current (unless otherwise noted)**

**power switch**

| PARAMETER                               | TEST<br>CONDITIONS† | MIN                    | TYP | MAX | UNIT |
|---|---------------------|------------------------|-----|-----|------|
|   |                     |                        |     |     |      |
| r <sub>DS(on)</sub> On-state resistance | IN1-OUT             | T <sub>J</sub> = 25°C  | 250 |     | mΩ   |
|   |                     | T <sub>J</sub> = 125°C | 350 | 435 |      |
|   | IN2-OUT             | T <sub>J</sub> = 25°C  | 1.3 |     | Ω    |
|   |                     | T <sub>J</sub> = 125°C | 1.5 | 2.4 |      |

† Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

# TPS2104, TPS2105 V<sub>AUX</sub> POWER-DISTRIBUTION SWITCHES

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**electrical characteristics over recommended operating junction temperature range,  
V<sub>I(IN1)</sub> = V<sub>I(IN2)</sub> = 5 V, I<sub>O</sub> = rated current (unless otherwise noted) (continued)**

## enable input ( $\overline{EN}$ and EN)

| PARAMETER       |                          | TEST CONDITIONS                     |  | MIN  | TYP | MAX | UNIT    |
|-----------------|--------------------------|-------------------------------------|--|------|-----|-----|---------|
| V <sub>IH</sub> | High-level input voltage | 2.7 V ≤ V <sub>I(INx)</sub> ≤ 5.5 V |  | 2    |     |     | V       |
| V <sub>IL</sub> | Low-level input voltage  | 2.7 V ≤ V <sub>I(INx)</sub> ≤ 5.5 V |  |      | 0.8 |     | V       |
| I <sub>I</sub>  | Input current            | TPS2104                             | $\overline{EN} = 0$ V or $\overline{EN} = V_I(IN_x)$ | -0.5 | 0.5 |     | $\mu A$ |
|                 |                          | TPS2105                             | EN = 0 V or EN = V <sub>I(INx)</sub>                 | -0.5 | 0.5 |     | $\mu A$ |

## supply current

| PARAMETER      |                | TEST CONDITIONS |                                       | MIN   | TYP  | MAX | UNIT    |
|----------------|----------------|-----------------|---------------------------------------|---|------|-----|---------|
| I <sub>I</sub> | Supply current | TPS2104         | $\overline{EN} = H$ ,<br>IN2 selected | T <sub>J</sub> = 25°C<br>-40°C ≤ T <sub>J</sub> ≤ 125°C | 0.75 |     | $\mu A$ |
|                |                |                 |                                       |   | 1.5  |     |         |
|                |                | TPS2105         | $\overline{EN} = L$ ,<br>IN1 selected | T <sub>J</sub> = 25°C<br>-40°C ≤ T <sub>J</sub> ≤ 125°C | 18   |     | $\mu A$ |
|                |                |                 |                                       |   | 35   |     |         |
|                | Supply current | TPS2105         | $\overline{EN} = L$ ,<br>IN2 selected | T <sub>J</sub> = 25°C<br>-40°C ≤ T <sub>J</sub> ≤ 125°C | 0.75 |     | $\mu A$ |
|                |                |                 |                                       |   | 1.5  |     |         |
|                |                | TPS2105         | $\overline{EN} = H$ ,<br>IN1 selected | T <sub>J</sub> = 25°C<br>-40°C ≤ T <sub>J</sub> ≤ 125°C | 18   |     | $\mu A$ |
|                |                |                 |                                       |   | 35   |     |         |

## switching characteristics, T<sub>J</sub> = 25°C, V<sub>I(IN1)</sub> = V<sub>I(IN2)</sub> = 5 V (unless otherwise noted)<sup>†</sup>

| PARAMETER        |  | TEST CONDITIONS <sup>†</sup> |                         | MIN   | TYP  | MAX | UNIT |         |
|------------------|--|------------------------------|-------------------------|---|------|-----|------|---------|
| t <sub>r</sub>   | Output rise time                           | IN1-OUT                      | V <sub>I(IN2)</sub> = 0 | C <sub>L</sub> = 1 $\mu F$ , I <sub>L</sub> = 500 mA  | 340  |     |      | $\mu s$ |
|                  |  |                              |                         | C <sub>L</sub> = 10 $\mu F$ , I <sub>L</sub> = 500 mA | 340  |     |      |         |
|                  |  |                              |                         | C <sub>L</sub> = 1 $\mu F$ , I <sub>L</sub> = 100 mA  | 312  |     |      |         |
|                  |  | IN2-OUT                      | V <sub>I(IN1)</sub> = 0 | C <sub>L</sub> = 1 $\mu F$ , I <sub>L</sub> = 100 mA  | 3.4  |     |      |         |
|                  |  |                              |                         | C <sub>L</sub> = 10 $\mu F$ , I <sub>L</sub> = 100 mA | 34   |     |      |         |
|                  |  |                              |                         | C <sub>L</sub> = 1 $\mu F$ , I <sub>L</sub> = 10 mA   | 3.5  |     |      |         |
| t <sub>f</sub>   | Output fall time                           | IN1-OUT                      | V <sub>I(IN2)</sub> = 0 | C <sub>L</sub> = 1 $\mu F$ , I <sub>L</sub> = 500 mA  | 6    |     |      | $\mu s$ |
|                  |  |                              |                         | C <sub>L</sub> = 10 $\mu F$ , I <sub>L</sub> = 500 mA | 108  |     |      |         |
|                  |  |                              |                         | C <sub>L</sub> = 1 $\mu F$ , I <sub>L</sub> = 100 mA  | 8    |     |      |         |
|                  |  | IN2-OUT                      | V <sub>I(IN1)</sub> = 0 | C <sub>L</sub> = 1 $\mu F$ , I <sub>L</sub> = 100 mA  | 100  |     |      |         |
|                  |  |                              |                         | C <sub>L</sub> = 10 $\mu F$ , I <sub>L</sub> = 100 mA | 990  |     |      |         |
|                  |  |                              |                         | C <sub>L</sub> = 1 $\mu F$ , I <sub>L</sub> = 10 mA   | 1000 |     |      |         |
| t <sub>PLH</sub> | Propagation delay time, low-to-high output | IN1-OUT                      | V <sub>I(IN2)</sub> = 0 |   | 55   |     |      | $\mu s$ |
|                  |  | IN2-OUT                      | V <sub>I(IN1)</sub> = 0 | C <sub>L</sub> = 10 $\mu F$ , I <sub>L</sub> = 100 mA | 1    |     |      |         |
| t <sub>PHL</sub> | Propagation delay time, high-to-low output | IN1-OUT                      | V <sub>I(IN2)</sub> = 0 |   | 1.5  |     |      | $\mu s$ |
|                  |  | IN2-OUT                      | V <sub>I(IN1)</sub> = 0 | C <sub>L</sub> = 10 $\mu F$ , I <sub>L</sub> = 100 mA | 50   |     |      |         |

<sup>†</sup> All timing parameters refer to Figure 2.

PARAMETER MEASUREMENT INFORMATION

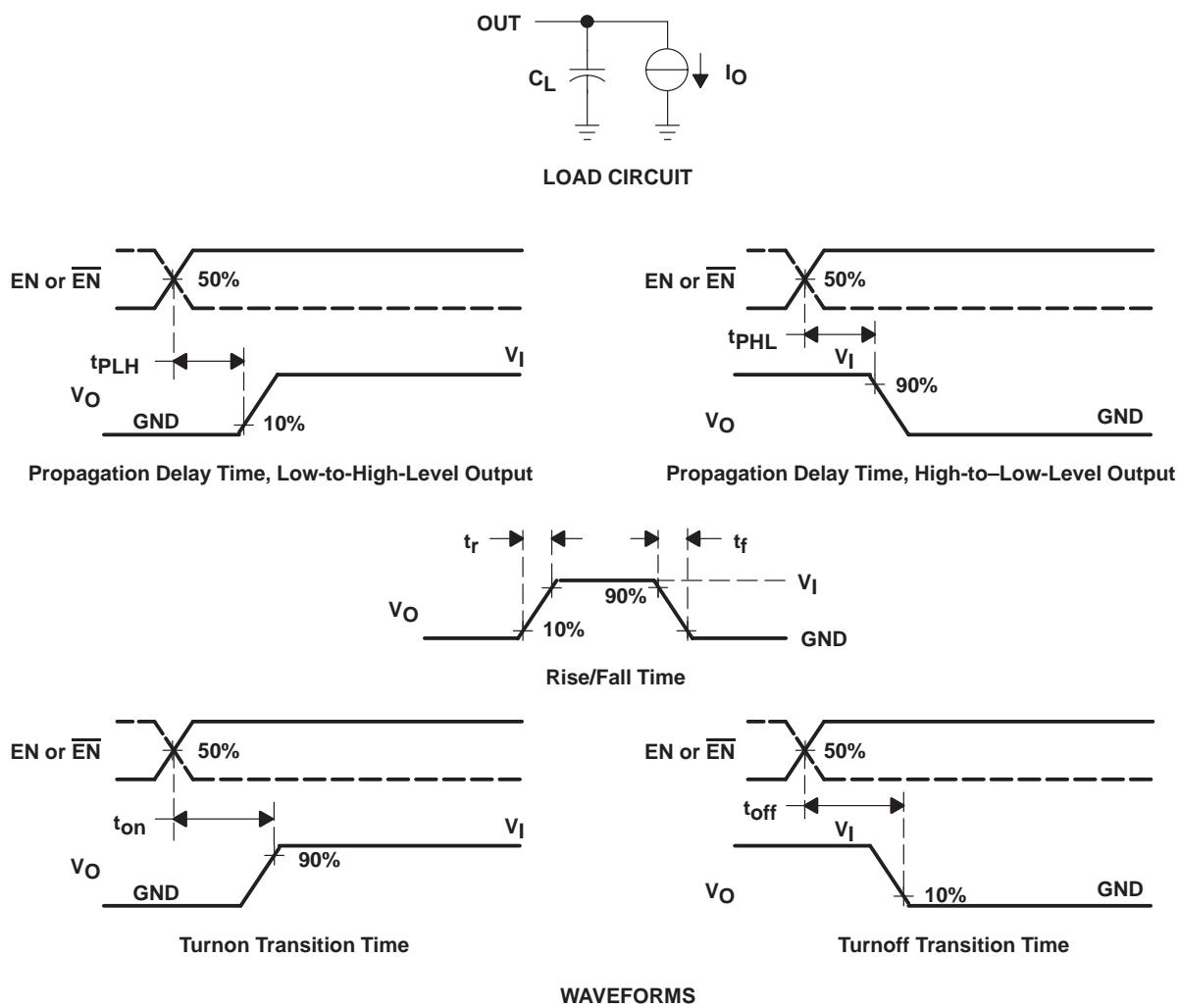


Figure 2. Test Circuit and Voltage Waveforms

Table of Timing Diagrams†

|   | FIGURE |
|---|--------|
| Propagation Delay and Rise Time With 1- $\mu$ F Load, IN1 | 3      |
| Propagation Delay and Rise Time With 1- $\mu$ F Load, IN2 | 4      |
| Propagation Delay and Fall Time With 1- $\mu$ F Load, IN1 | 5      |
| Propagation Delay and Fall Time With 1- $\mu$ F Load, IN2 | 6      |

† Waveforms shown in Figures 3–6 refer to TPS2104 at  $T_J = 25^\circ\text{C}$

# TPS2104, TPS2105 V<sub>AUX</sub> POWER-DISTRIBUTION SWITCHES

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## PARAMETER MEASUREMENT INFORMATION

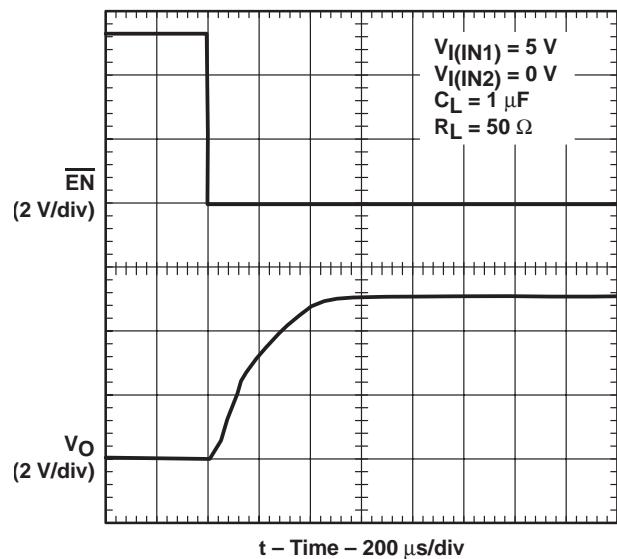


Figure 3. Propagation Delay and Rise Time With 1- $\mu$ F Load, IN1 Turnon

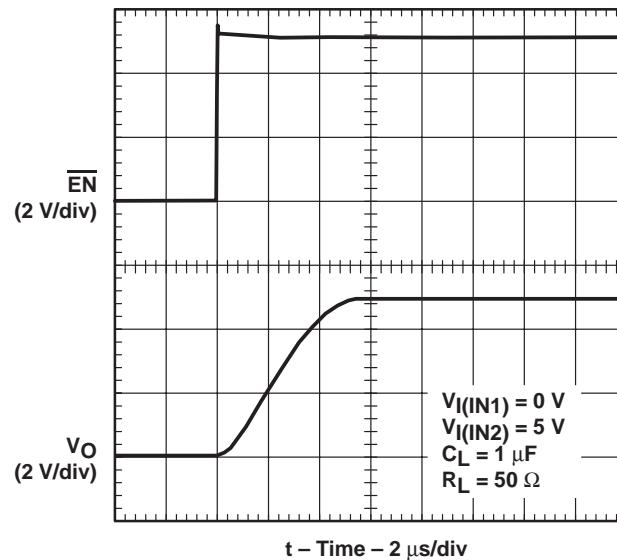


Figure 4. Propagation Delay and Rise Time With 1- $\mu$ F Load, IN2 Turnon

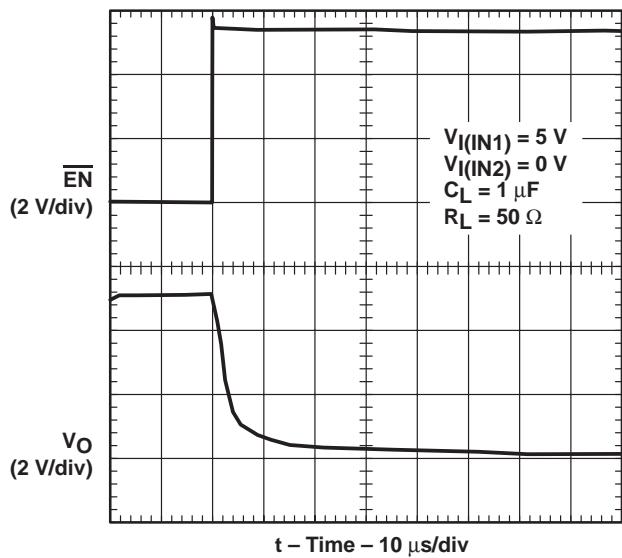


Figure 5. Propagation Delay and Fall Time With 1- $\mu$ F Load, IN1 Turnoff

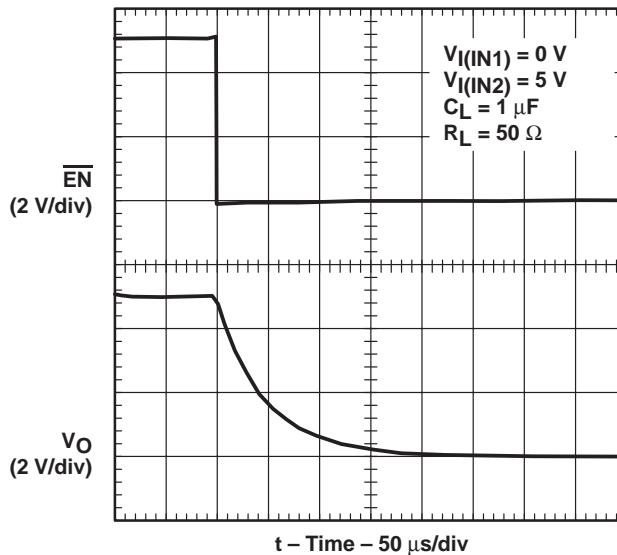


Figure 6. Propagation Delay and Fall Time With 1- $\mu$ F Load, IN2 Turnoff

**TYPICAL CHARACTERISTICS**

**Table of Graphs**

|                             |   | FIGURE |
|-----------------------------|---|--------|
| IN1 Switch Rise Time        | vs Output Current   | 7      |
| IN2 Switch Fall Time        | vs Output Current   | 8      |
| IN1 Switch Fall Time        | vs Output Current   | 9      |
| IN2 Switch Fall Time        | vs Output Current   | 10     |
| Output Voltage Droop        | vs Output Current When Output Is Switched From IN2 to IN1 | 11     |
| Inrush Current              | vs Output Capacitance                                     | 12     |
| IN1 Supply Current          | vs Junction Temperature (IN1 Enabled)                     | 13     |
| IN1 Supply Current          | vs Junction Temperature (IN1 Disabled)                    | 14     |
| IN2 Supply Current          | vs Junction Temperature (IN2 Enabled)                     | 15     |
| IN2 Supply Current          | vs Junction Temperature (IN2 Disabled)                    | 16     |
| IN1-OUT On-State Resistance | vs Junction Temperature                                   | 17     |
| IN2-OUT On-State Resistance | vs Junction Temperature                                   | 18     |

**IN1 SWITCH RISE TIME  
vs  
OUTPUT CURRENT**

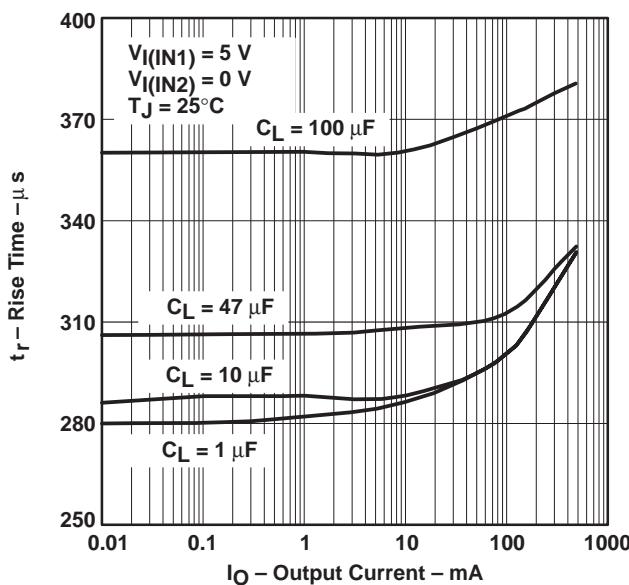


Figure 7

**IN2 SWITCH RISE TIME  
vs  
OUTPUT CURRENT**

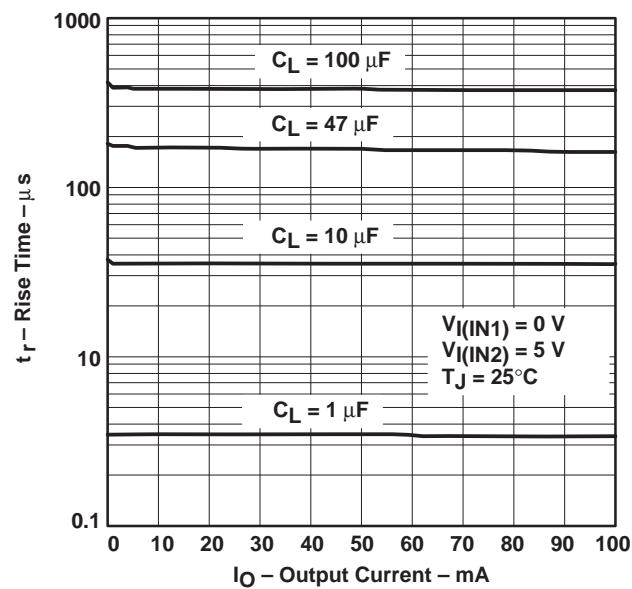


Figure 8

# TPS2104, TPS2105 V<sub>AUX</sub> POWER-DISTRIBUTION SWITCHES

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## TYPICAL CHARACTERISTICS

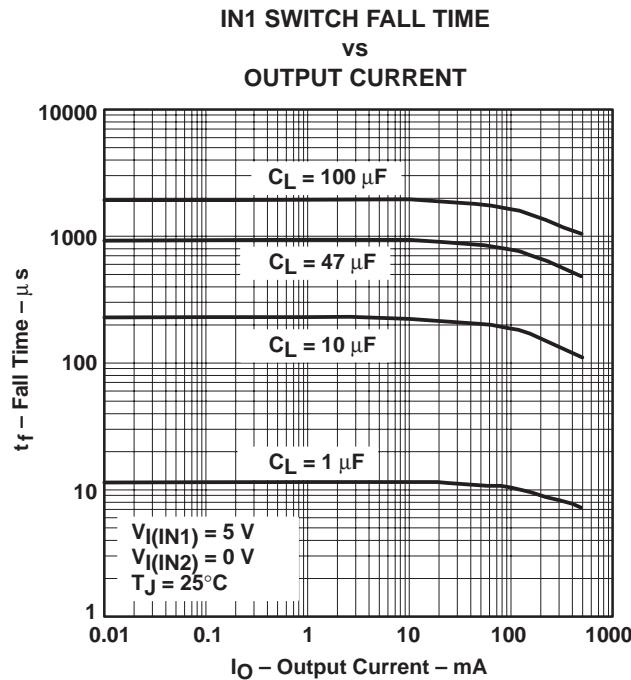


Figure 9

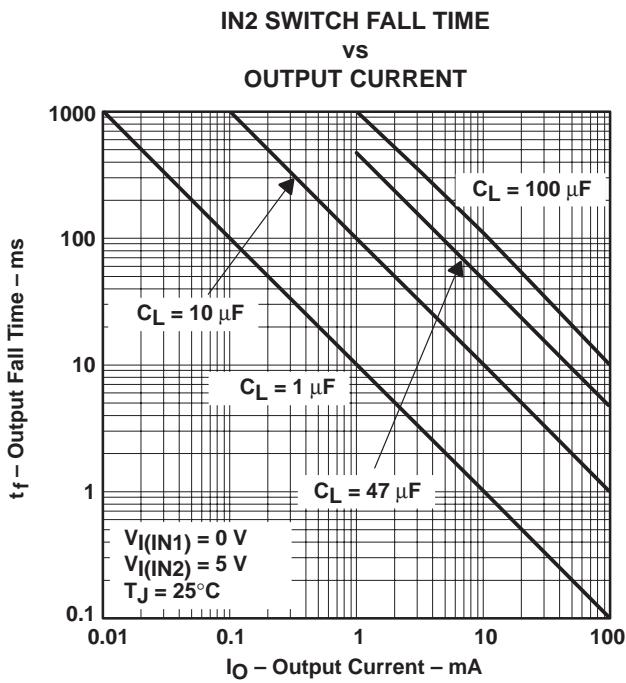


Figure 10

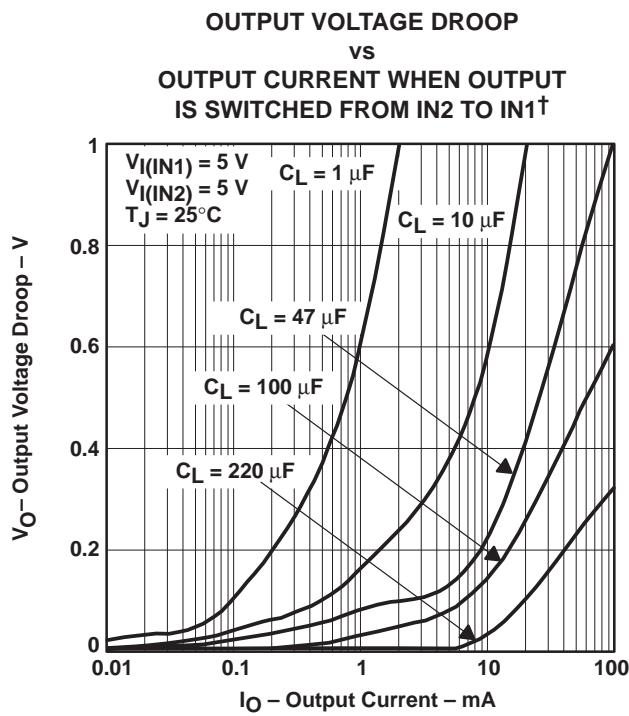


Figure 11

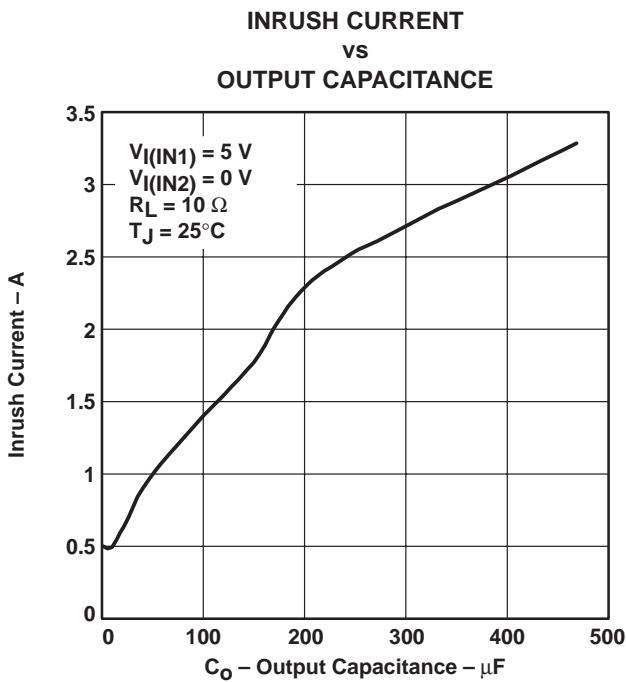


Figure 12

<sup>†</sup> If switching from IN1 to IN2, the voltage droop is much smaller. Therefore, the load capacitance should be chosen according to the curves in Figure 15.

TYPICAL CHARACTERISTICS

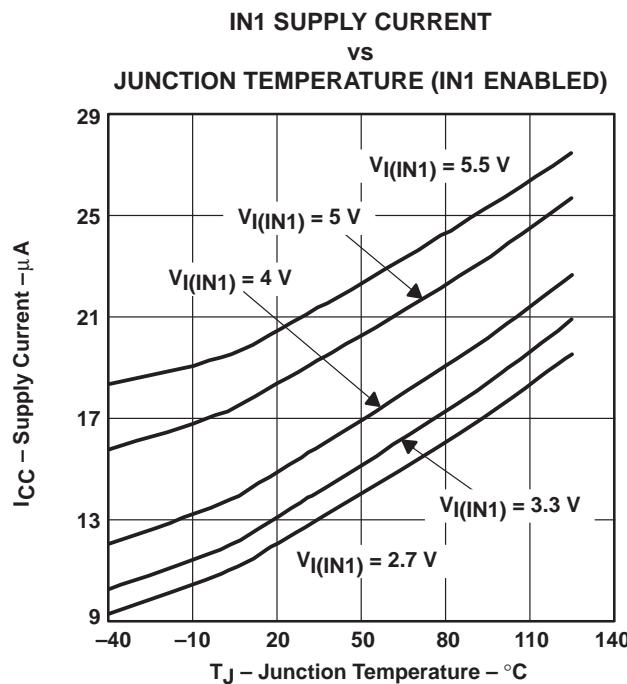


Figure 13

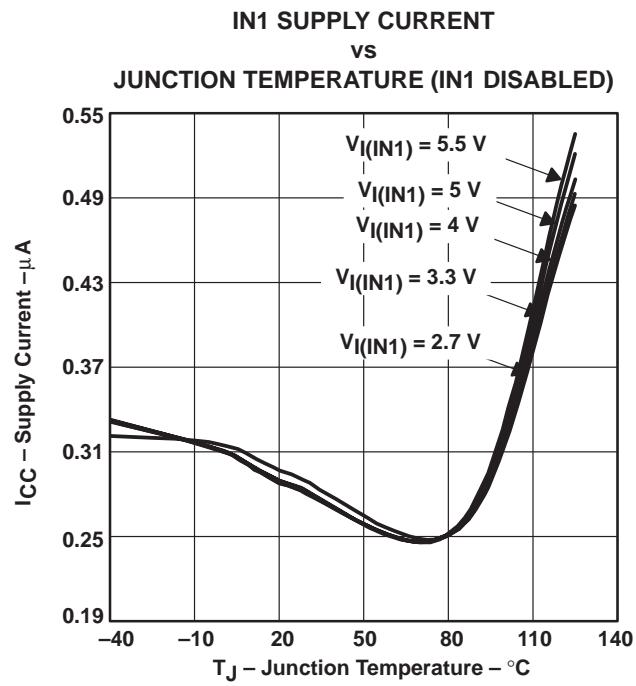


Figure 14

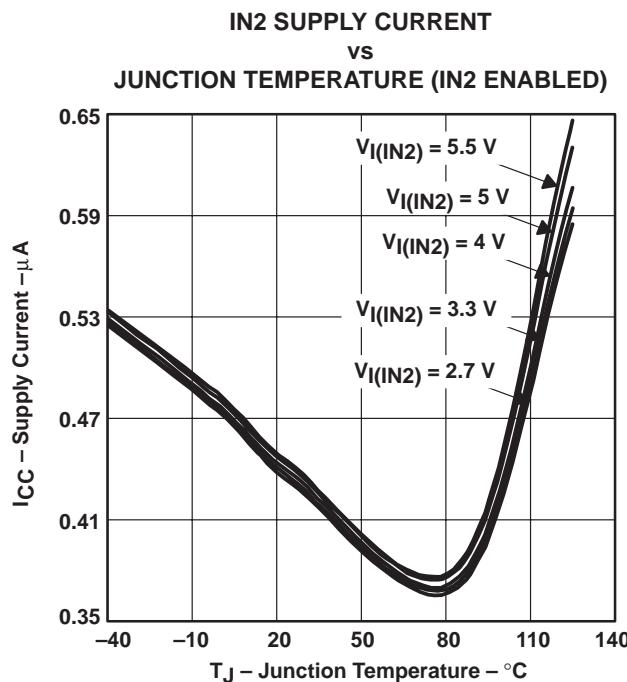


Figure 15

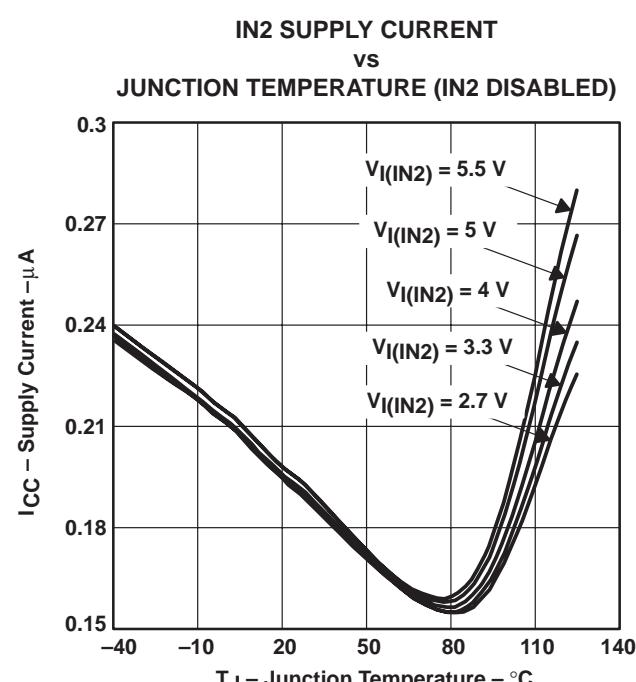


Figure 16

# TPS2104, TPS2105 V<sub>AUX</sub> POWER-DISTRIBUTION SWITCHES

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## TYPICAL CHARACTERISTICS

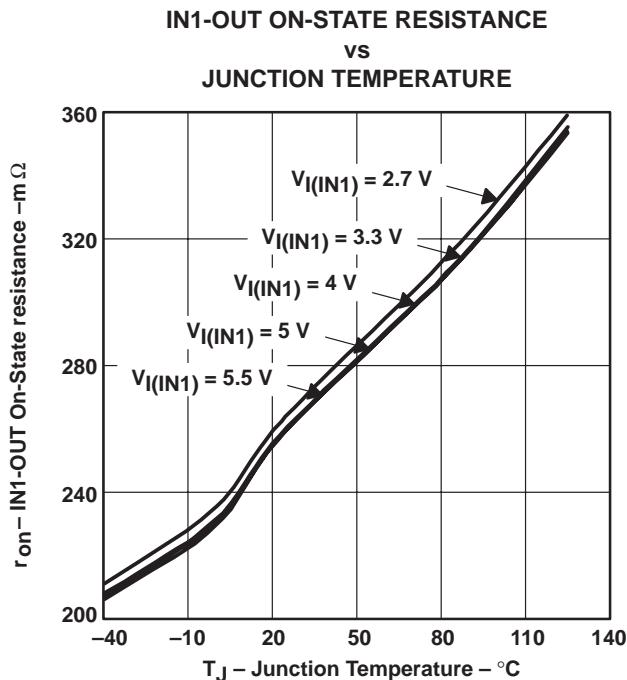


Figure 17

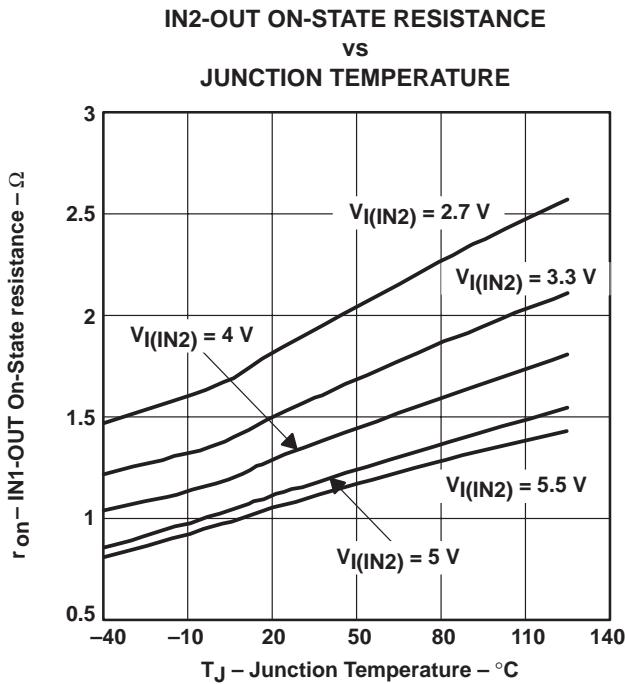


Figure 18

## APPLICATION INFORMATION

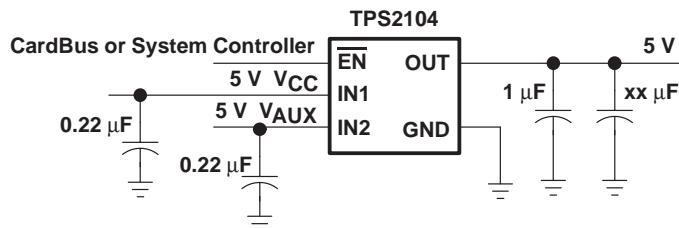


Figure 19. Typical Application

## power-supply considerations

A 0.22- $\mu$ F ceramic bypass capacitor between IN and GND, close to the device is recommended. The output capacitor should be chosen based on the size of the load during the transition of the switch. A 220- $\mu$ F capacitor is recommended for 100-mA loads. Typical output capacitors (xx  $\mu$ F, shown in Figure 19) required for a given load can be determined from Figure 11 which shows the output voltage droop when output is switched from IN2 to IN1. The output voltage droop is insignificant when output is switched from IN1 to IN2. Additionally, bypassing the output with a 1- $\mu$ F ceramic capacitor improves the immunity of the device to short-circuit transients.

## APPLICATION INFORMATION

### power supply considerations (continued)

#### switch transition

The n-channel MOSFET on IN1 uses a charge pump to create the gate-drive voltage, which gives the IN1 switch a rise time of approximately 0.4 ms. The p-channel MOSFET on IN2 has a simpler drive circuit that allows a rise time of approximately 4  $\mu$ s. Because the device has two switches and a single enable pin, these rise times are seen as transition times, from IN1 to IN2, or IN2 to IN1, by the output. The controlled transition times help limit the surge currents seen by the power supply during switching.

#### thermal protection

Thermal protection provided on the IN1 switch prevents damage to the IC when heavy-overload or short-circuit faults are present for extended periods of time. The increased dissipation causes the junction temperature to rise to dangerously high levels. The protection circuit senses the junction temperature of the switch and shuts it off at approximately 145°C ( $T_J$ ). The switch remains off until the junction temperature has dropped approximately 10°C. The switch continues to cycle in this manner until the load fault or input power is removed.

#### undervoltage lockout

An undervoltage lockout function is provided to ensure that the power switch is in the off state at power up. Whenever the input voltage falls below approximately 2 V, the power switch quickly turns off. This function facilitates the design of hot-insertion systems that may not have the capability to turn off the power switch before input power is removed. Upon reinsertion, the power switch will be turned on with a controlled rise time to reduce EMI and voltage overshoots.

### power dissipation and junction temperature

The low on-resistance on the n-channel MOSFET allows small surface-mount packages, such as SOIC, to pass large currents. The thermal resistances of these packages are high compared to those of power packages; it is good design practice to check power dissipation and junction temperature. First, find  $r_{on}$  at the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read  $r_{on}$  from Figure 17 or Figure 18. Next calculate the power dissipation using:

$$P_D = r_{on} \times I^2$$

Finally, calculate the junction temperature:

$$T_J = P_D \times R_{\theta JA} + T_A$$

Where:

$T_A$  = Ambient temperature

$R_{\theta JA}$  = Thermal resistance

Compare the calculated junction temperature with the initial estimate. If they do not agree within a few degrees, repeat the calculation using the calculated value as the new estimate. Two or three iterations are generally sufficient to obtain a reasonable answer.

### ESD protection

All TPS2104 and TPS2105 terminals incorporate ESD-protection circuitry designed to withstand a 2-kV human-body-model, 750-V CDM, and 200-V machine-model discharge as defined in MIL-STD-883C.

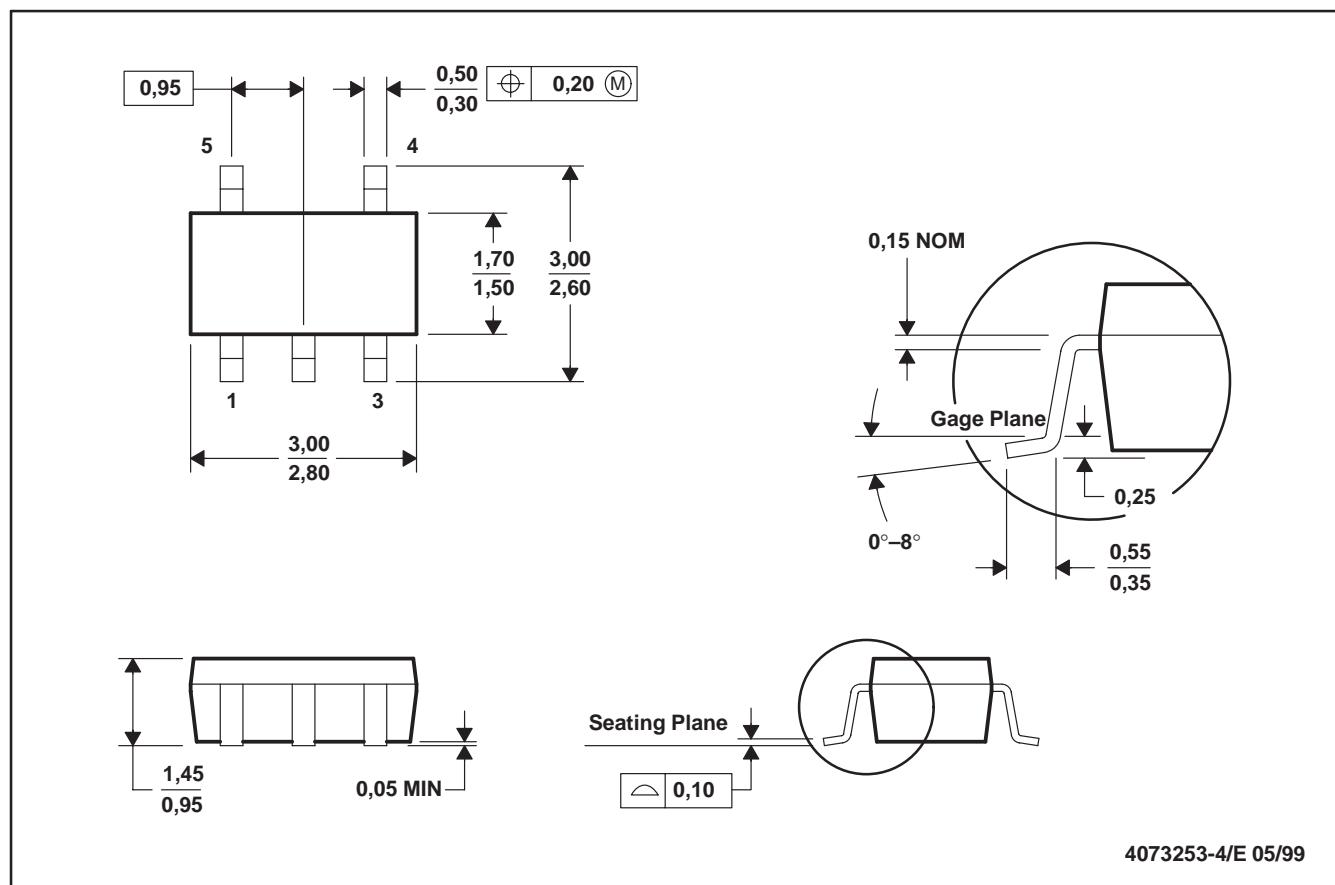
**TPS2104, TPS2105  
V<sub>AUX</sub> POWER-DISTRIBUTION SWITCHES**

SLVS235A – SEPTEMBER 1999 – REVISED APRIL 2000

**MECHANICAL DATA**

**DBV (R-PDSO-G5)**

**PLASTIC SMALL-OUTLINE**



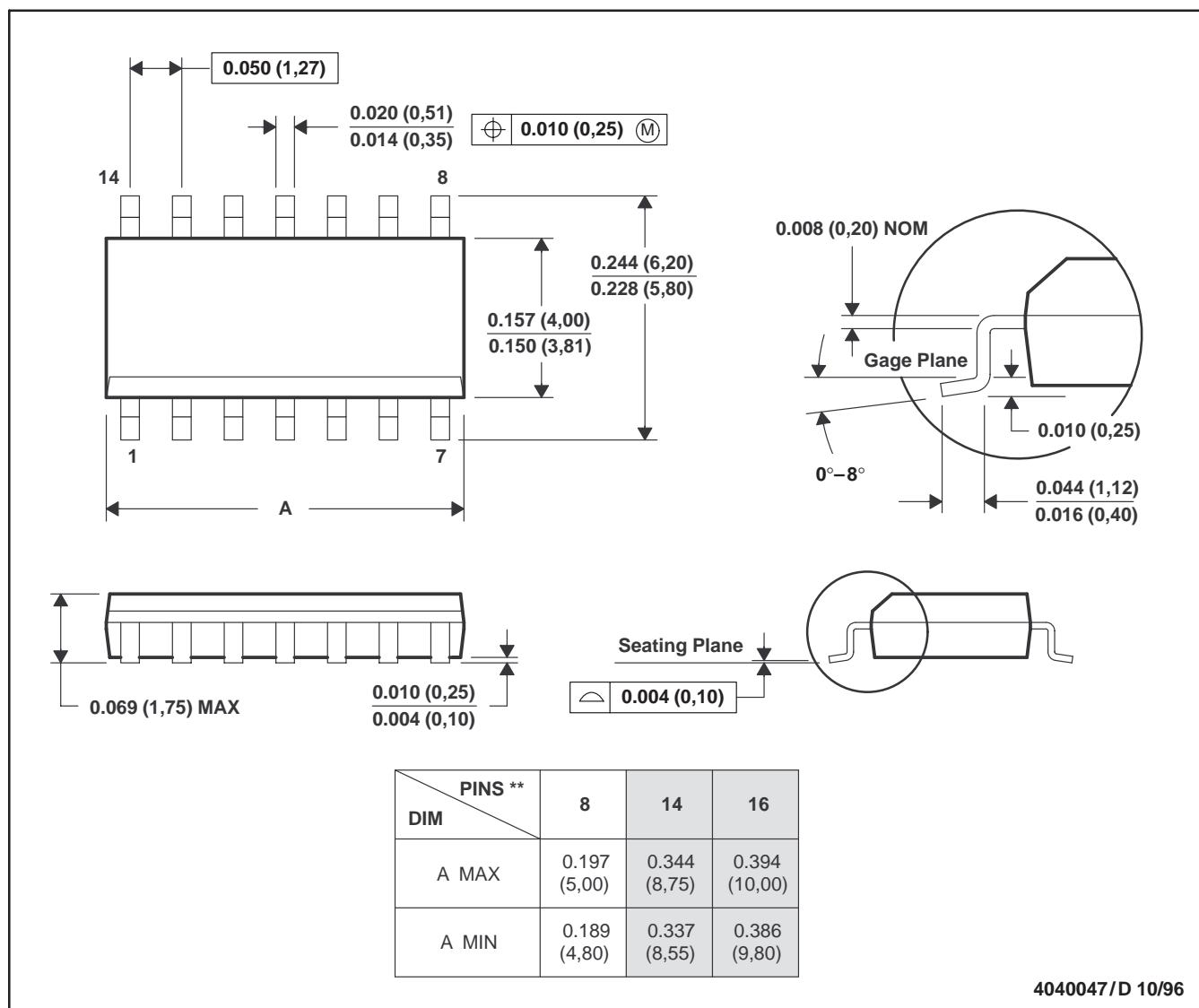
NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion.  
 D. Falls within JEDEC MO-178

MECHANICAL DATA

D (R-PDSO-G\*\*)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0.15).  
 D. Falls within JEDEC MS-012

**PACKAGING INFORMATION**

| Orderable Device | Status <sup>(1)</sup> | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <sup>(2)</sup> | Lead/Ball Finish | MSL Peak Temp <sup>(3)</sup> |
|------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|------------------|------------------------------|
| TPS2104DBVR      | ACTIVE                | SOT-23       | DBV             | 5    | 3000        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TPS2104DBVRG4    | ACTIVE                | SOT-23       | DBV             | 5    | 3000        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TPS2104DBVT      | ACTIVE                | SOT-23       | DBV             | 5    | 250         | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TPS2104DBVTG4    | ACTIVE                | SOT-23       | DBV             | 5    | 250         | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TPS2105D         | ACTIVE                | SOIC         | D               | 8    | 75          | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TPS2105DBVR      | ACTIVE                | SOT-23       | DBV             | 5    | 3000        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TPS2105DBVRG4    | ACTIVE                | SOT-23       | DBV             | 5    | 3000        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TPS2105DBVT      | ACTIVE                | SOT-23       | DBV             | 5    | 250         | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TPS2105DBVTG4    | ACTIVE                | SOT-23       | DBV             | 5    | 250         | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| TPS2105DG4       | ACTIVE                | SOIC         | D               | 8    | 75          | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

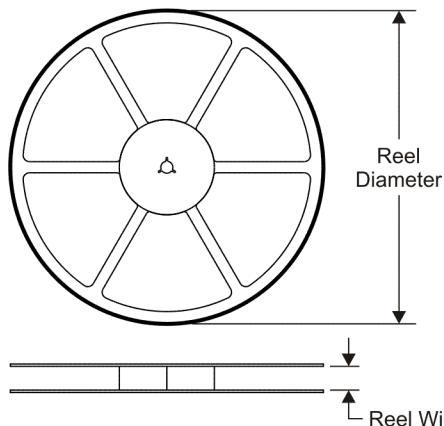
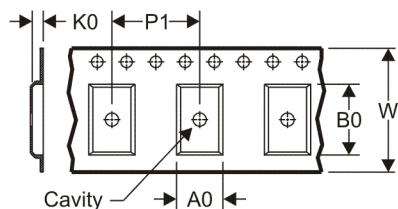
**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

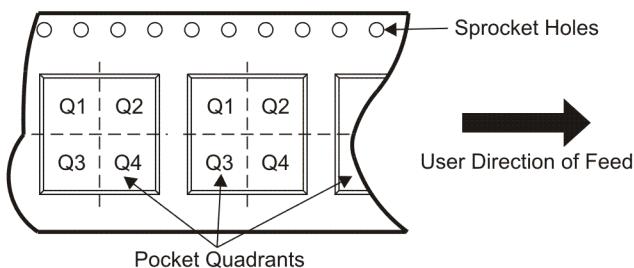
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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**TAPE AND REEL INFORMATION**
**REEL DIMENSIONS**

**TAPE DIMENSIONS**


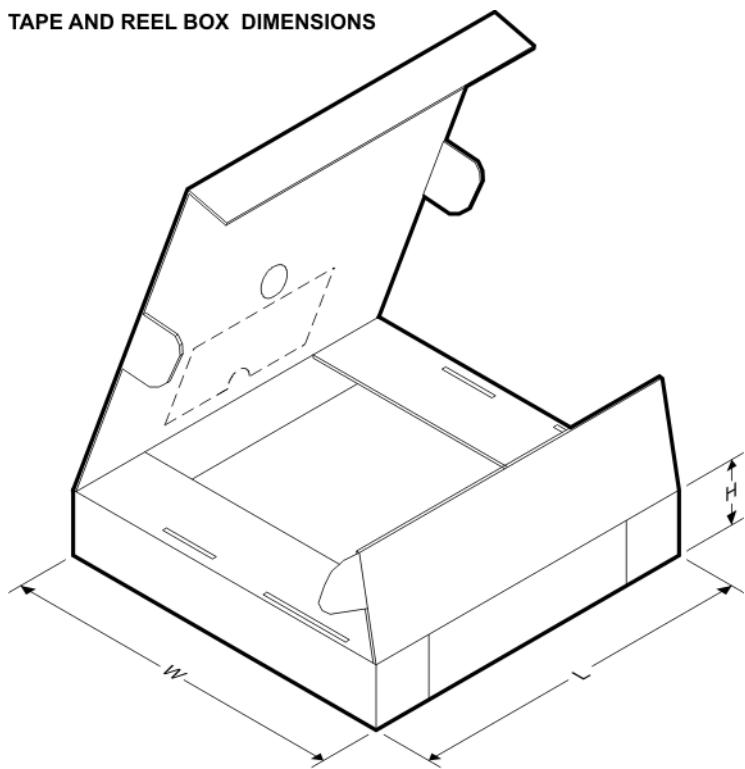
|    |   |
|----|---|
| A0 | Dimension designed to accommodate the component width     |
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

| Device      | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS2104DBVR | SOT-23       | DBV             | 5    | 3000 | 180.0              | 9.0                | 3.15    | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2104DBVT | SOT-23       | DBV             | 5    | 250  | 180.0              | 9.0                | 3.15    | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2105DBVR | SOT-23       | DBV             | 5    | 3000 | 180.0              | 9.0                | 3.15    | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2105DBVT | SOT-23       | DBV             | 5    | 250  | 180.0              | 9.0                | 3.15    | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |

**TAPE AND REEL BOX DIMENSIONS**



\*All dimensions are nominal

| Device      | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS2104DBVR | SOT-23       | DBV             | 5    | 3000 | 182.0       | 182.0      | 20.0        |
| TPS2104DBVT | SOT-23       | DBV             | 5    | 250  | 182.0       | 182.0      | 20.0        |
| TPS2105DBVR | SOT-23       | DBV             | 5    | 3000 | 182.0       | 182.0      | 20.0        |
| TPS2105DBVT | SOT-23       | DBV             | 5    | 250  | 182.0       | 182.0      | 20.0        |

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